

MBRF10100CT(LS)

SCHOTTKY BARRIER RECTIFIER

REVERSE VOLTAGE - 100 Volts FORWARD CURRENT - 10 Amperes

ITO-220AB

FEATURES

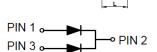
- Metal of silicon rectifier, majority carrier conduction
- · Guard ring for transient protection
- Low power loss, high efficiency
- High current capability, low V_F
- · High surge capacity
- Plastic package has UL flammability classification 94V-0
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- IEC 61000-4-2, level 4 (ESD), >15KV (air)
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

MECHANICAL DATA

Package: ITO-220AB molded plastic
Polarity: AS marked on the body
Weight: 0.06 ounces, 1.70 grams

Mounting position: Any

• Max. mounting torque = 0.5N.m (5.1Kgf.cm)



ITO-220AB				
DIM	MIN MAX			
Α	15.50	16.50		
В	10.00	10.40		
С	3.00	3.50		
D	9.00	9.30		
Е	2.90	3.60		
F	13.46	14.22		
G	1.15	1.70		
Н	2.40	2.70		
ı	0.75	1.00		
J	0.45	0.70		
K	3.00 Ø	3.30 Ø		
L	4.36	4.77		
M	2.48	2.80		
N	2.50	2.80		

All dimension in millimeter

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

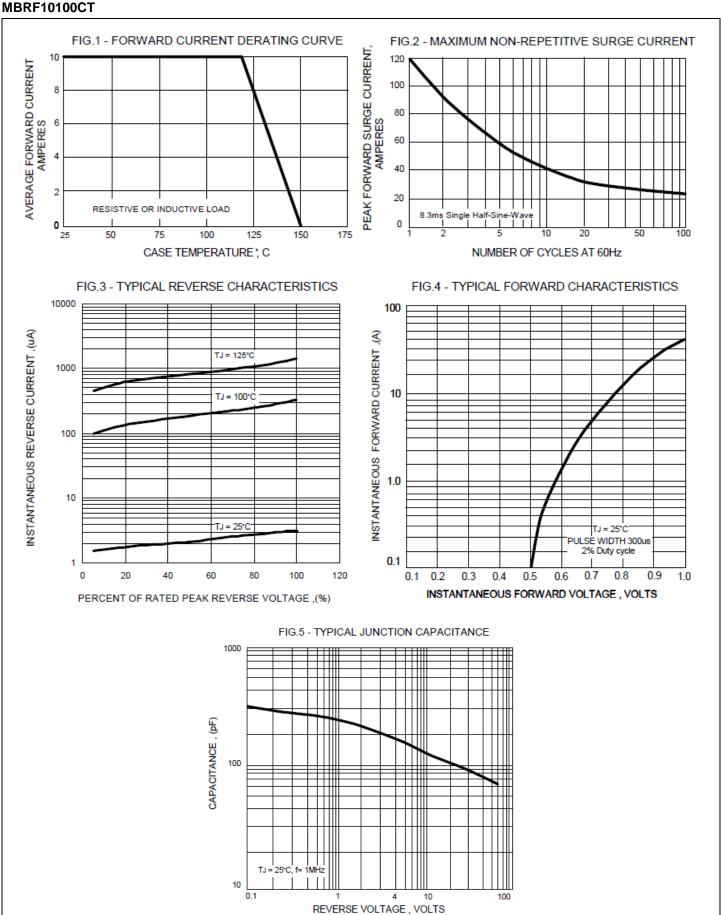
CHARACTERISTICS		SYMBOL	VALUE	UNIT
Maximum Recurrent Peak Reverse V	oltage @IR=100uA	Vrrm	100	V
Maximum RMS Voltage	@IR=100uA	VRMS	70	V
Maximum DC Blocking Voltage	@IR=100uA	VDC	100	V
Maximum Average Forward Rectified Current at T _C =120°C (See Fig.4)		I(AV)	10	А
Peak Forward Surge Current 8.3ms single half sine-wave	@TJ=25°C	IFSM	120	А
Peak Repetitive Reverse Current tp=2us, square F=1KHz	@T _J =25°C	IRRM	1	А
Voltage Rate of Change (Rated VR)		dv/dt	10000	V/us
Maximum Forward Voltage (Note 4)	@IF=5A TJ=25 °C @IF=5A TJ=125 °C @IF=10A TJ=25 °C @IF=10A TJ=125 °C	VF	0.85 0.75 0.95 0.85	V
Maximum DC Reverse Current at Rated DC Blocking Voltage	@TJ=25 °C @TJ=125 °C	IR	0.01 15	mA
Typical Junction Capacitance per element (Note 5)		Cı	180	pF
Typical Thermal Resistance (Note 6)		Rejc	3.0	°C/W
Operating Temperature Range		TJ,	-55 to +150	°C
Storage Temperature Range		Tstg	-55 to +175	°C
Dielectric Strength from terminals to case, AC with t=1 minute, RH<30%		Vdis	2000	V

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. 300us pulse width, 2% duty cycle.
- 5. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 6. Thermal Resistance Junction to Case. Device mounted on 135mm x 135mm x 8mm Al Plate.



RATING AND CHARACTERISTIC CURVES

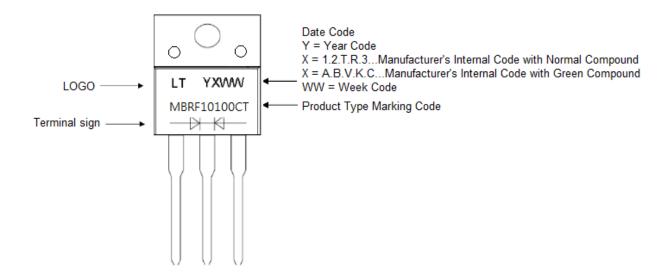




Ordering Information:

Part Number	Package	Packing	
		Qty.	Carrier
MBRF10100CT-LS	ITO-220AB	50pcs	Tube

Marking Information:



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